**PNP/NPN Epitaxial Planar Silicon Transistors** 



2SA1527/2SC3921

# Switching Applications (with Bias Resistance)

### **Applications**

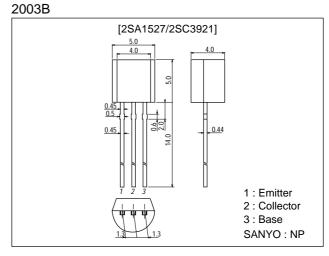
• Switching circuits, inverter circuits, interface circuits, driver circuits.

### **Features**

- · On-chip bias resistance : R1=4.7k $\Omega$ , R2=4.7k $\Omega$ .
- $\cdot$  Large current capacity : I<sub>C</sub>=500mA.

## **Package Dimensions**

unit:mm



():2SA1527

### **Specifications**

#### Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(–)50	V
Collector-to-Emitter Voltage	VCEO		(–)50	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		()6	V
Collector Current	I <sub>C</sub>		(–)500	mA
Collector Current (Pulse)	ICP		(–)800	mA
Collector Dissipation	PC		600	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### **Electrical Characteristics** at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V <sub>CB</sub> =(-)40V, I <sub>E</sub> =0			(–)0.1	μA
	ICEO	V <sub>CE</sub> =(-)40V, I <sub>B</sub> =0			(–)0.5	μA
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =(-)5V, I <sub>C</sub> =0	(–)410	(–)532	(–)760	μA
DC Current Gain	hFE	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)20mA	50			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)5mA		250		MHz
				(200)		MHz

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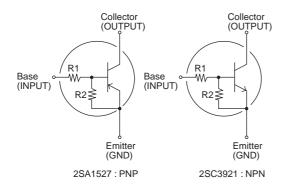
SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

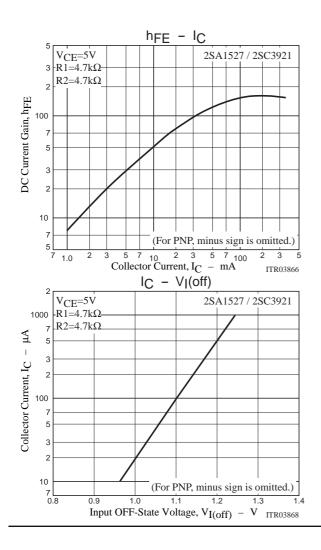
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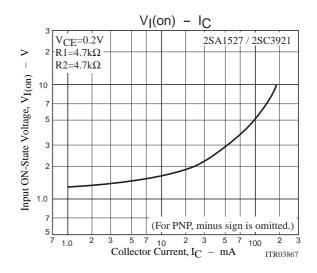
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)10V, f=1MHz		3.7		pF
				(5.5)		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(-)40mA, I <sub>B</sub> =(-)2mA		(–)0.1	(–)0.3	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =(-)10µA, I <sub>E</sub> =0	(–)50			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =(–)100µA, R <sub>BE</sub> =∞	(–)50			V
Input OFF-State Voltage	V <sub>I(off)</sub>	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)100µA	(–)0.8	(–)1.1	(–)1.5	V
Input ON-State Voltage	V <sub>I(on)</sub>	V <sub>CE</sub> =(-)0.2V, I <sub>C</sub> =(-)20mA	(–)1.0	(–)1.9	(–)4.0	V
Input Resistance	R1		3.3	4.7	6.1	kΩ
Resistance Ratio	R1/R2		0.9	1.0	1.1	

#### **Electrical Connection**







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